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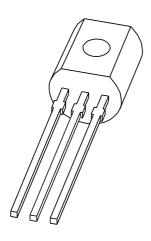
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DISCRETE SEMICONDUCTORS

DATA SHEET



2PA1015PNP general purpose transistor

Product specification Supersedes data of 1999 Apr 08 2004 Oct 11





PNP general purpose transistor

2PA1015

FEATURES

- Low current (max. 150 mA)
- Low voltage (max. 50 V).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

PNP transistor in a plastic TO-92; SOT54 package. NPN complement: 2PC1815.

PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter

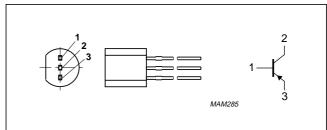


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

ORDERING INFORMATION

TYPE NUMBER		PACKAGE	
TIPE NOWIBER	NAME	DESCRIPTION	VERSION
2PA1015Y	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54
2PA1015GR			

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-50	V
V _{CEO}	collector-emitter voltage	open base	_	-50	V
V _{EBO}	emitter-base voltage	open collector	_	- 5	V
I _C	collector current (DC)		_	-150	mA
I _{CM}	peak collector current		_	-200	mA
I _{BM}	peak base current		_	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

PNP general purpose transistor

2PA1015

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS		TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	_	_	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	_	_	-100	nA
h _{FE}	DC current gain	$V_{CE} = -6 \text{ V}; I_{C} = -2 \text{ mA}$				
	2PA1015Y		120	_	240	
	2PA1015GR		200	_	400	
h _{FE}	DC current gain	$V_{CE} = -6 \text{ V}; I_{C} = -150 \text{ mA}$		_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -100 \text{ mA}; I_B = -10 \text{ mA}$	_	_	-300	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -100 \text{ mA}; I_B = -10 \text{ mA}$	_	_	-1.1	V
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	_	4	7	pF
f _T	transition frequency	$V_{CB} = -10 \text{ V}; I_C = -1 \text{ mA}; f = 100 \text{ MHz}$	80	_	_	MHz
F	noise figure	$V_{CE} = -5 \text{ V; } I_{C} = -200 \mu\text{A; } R_{S} = 2 k\Omega;$ f = 1 kHz; B = 200 Hz	_	_	10	dB

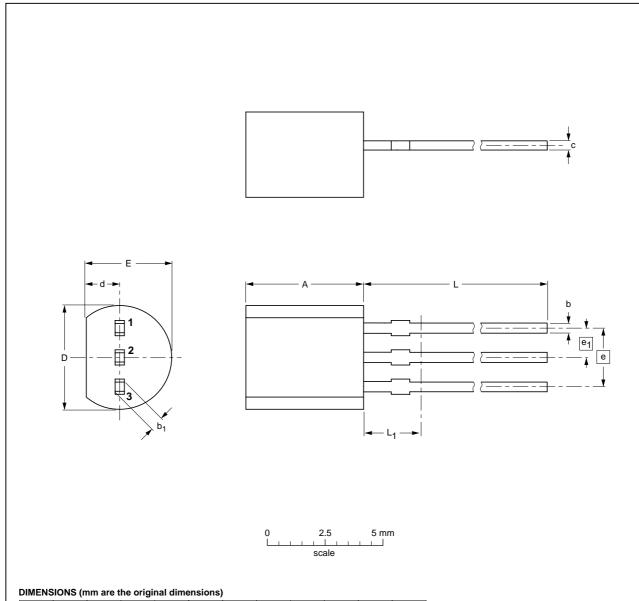
PNP general purpose transistor

2PA1015

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	A	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			97-02-28 04-06-28

PNP general purpose transistor

2PA1015

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LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
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